

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L22	2004	(438/22).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 13:26
L23	371	22 and (buffer same (GaN (gallium near2 nitride)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 13:27
L24	164	22 and (buffer same (GaN (gallium near2 nitride))) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 13:38
L25	438	(438/34).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 13:38
L26	11	25 and (buffer same (GaN (gallium near2 nitride))) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 13:49
L27	130	(438/35).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 13:49
L28	238	(438/41).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 13:49

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L29	10	28 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 13:50
L30	222	(438/44).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 13:50
L31	11	30 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 13:51
L32	1039	(438/46).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 14:25
L33	147	32 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 14:25
L34	728	(438/47).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 14:25
L35	88	34 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 14:34

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L36	409	(438/69).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 14:33
L37	2	36 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 14:59
L38	282	(438/93).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 14:44
L39	206	(438/606).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 14:59
L40	391	(257/15).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 14:59
L41	18	40 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 15:06
L42	2221	(257/79).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 15:06

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L43	199	42 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 15:28
L44	1183	(257/88).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 15:28
L45	36	44 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 16:22
L46	2700	(257/103).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 15:33
L47	359	46 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 16:07
L48	315	47 and (InN (indium near2 nitride) InGaN (indium near2 gallium near2 nitride) AlInGaN (aluminum near2 indium near2 gallium near2 nitride))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 16:06
L49	425	(257/613).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 16:06

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L50	18	49 and (buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 16:15
L51	19	(257/E21.053).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 16:16
L52	11	(257/E21.351).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 16:17
L53	82	(257/E21.352).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 16:20
L54	6	(257/E21.365).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 16:20
L55	15	(257/E21.366).CCLS.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/12/06 16:20
L56	797	(buffer same (GaN (gallium near2 nitride)) same (three multiple plurality stack\$3)) same (InN (indium near2 nitride) InGaN (indium near2 gallium near2 nitride) AlInGaN (aluminum near2 indium near2 gallium near2 nitride))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 16:41

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L57	38	56 and (buffer same (three adj (layer\$2 structur\$3)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/12/06 16:24
L58	1	((GaN (gallium near2 nitride)) near2 buffer) and (three adj layer\$2 adj structure) and (single near2 crystal\$4) and substrate and (nitride near2 semiconductor)).clm.	US-PGPUB	OR	ON	2007/12/06 16:44